

UG3KB60-E-43L THRU UG3KB80-E-43L

SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIER

Voltage: 600 to 800V

Current: 3.0A



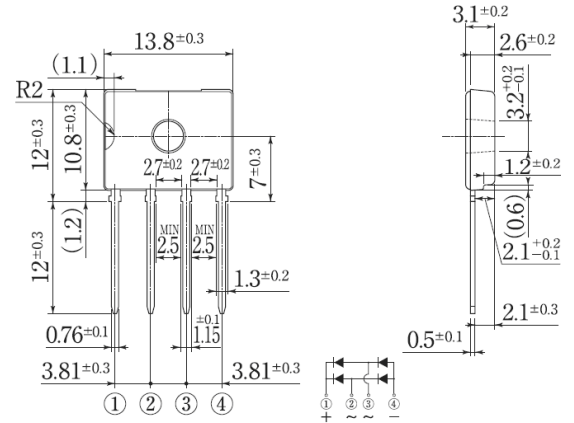
Features

Glass passivated chip junction
 High case dielectric strength
 High surge current capability
 Ideal for printed circuit board
 This series is UL listed under Recognized Component Index, file number E330278
 Halogen Free

Mechanical Data

Terminal: Plated leads solderable per J-STD-002
 Case: Halogen Free Epoxy
 Polarity: Polarity symbol marked on body
 Mounting position: any

D3K



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half -wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

	Symbol	UG3KB60-E-43L	UG3KB80-E-43L	units
Maximum repetitive peak reverse voltage	V _{rrm}	600	800	V
Maximum RMS voltage	V _{rms}	420	560	V
Maximum DC blocking voltage	V _{dc}	600	800	V
Maximum average forward rectified output current T _c 140°C with heatsink	I _{f(av)}	3.0		A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	I _{fsm}	90		A
Maximum instantaneous forward voltage drop per leg at 1.5A	V _f	1.05		V
Rating for fusing (3ms ≤ t < 8.3ms)	I ² t	35		A ² Sec
Maximum DC reverse current at rated DC blocking voltage per leg	I _r	10.0 500		μA
Thermal resistance	without heatsink	55		°C/W
	with heatsink	1.5		
	without heatsink	15		
Operating junction and storage temperature range	T _j , T _{stg}	-55 to +150		°C

Note:

RATINGS AND CHARACTERISTIC CURVES UG3KB60-E-43L THRU UG3KB80-E-43L

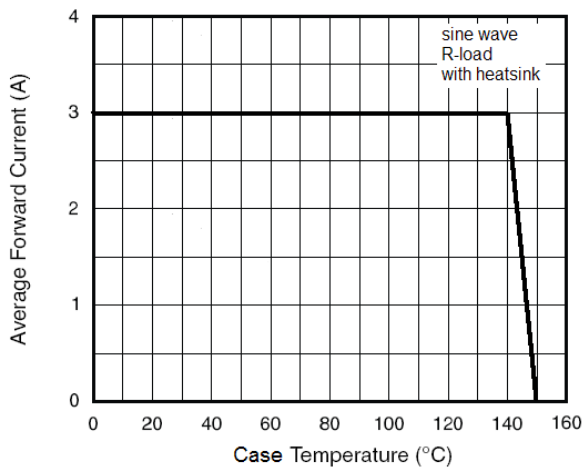


Figure 1. Forward Current Derating Curve

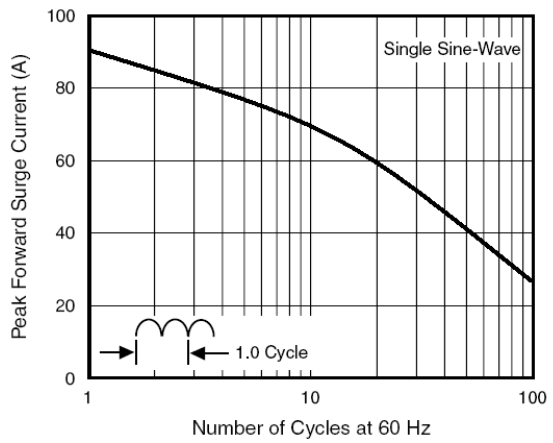


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

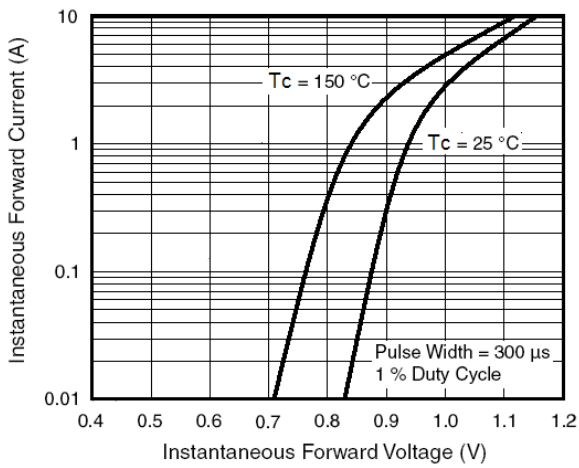


Figure 3. Typical Forward Characteristics Per Diode

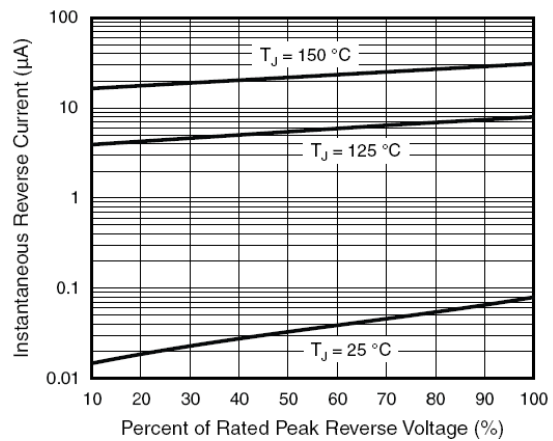


Figure 4. Typical Reverse Leakage Characteristics Per Diode

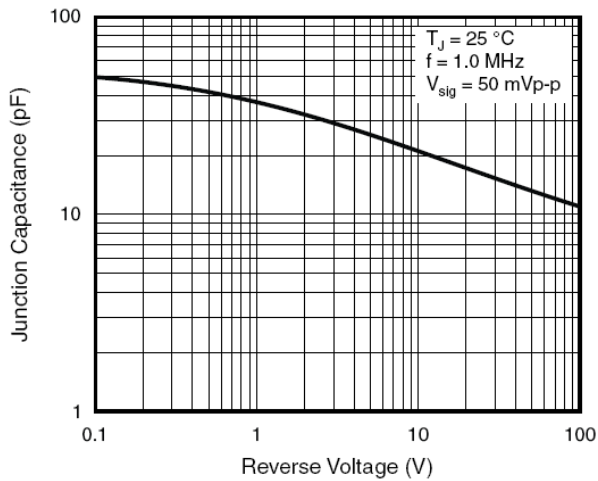


Figure 5. Typical Junction Capacitance Per Diode